1

Vishay Semiconductors

Schottky Rectifier, 10 A



•	low	forward	voltage	drop
•	LOW	lorward	voitage	arop

- Guard ring for enhanced ruggedness and long term reliability
- Popular D-PAK outline
- Small foot print, surface mountable
- High frequency operation
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-10WQ045FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

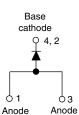
MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	10	А				
V _{RRM}		45	V				
I _{FSM}	$t_p = 5 \ \mu s \ sine$	400	А				
V _F	10 A _{pk} , T _J = 125 °C	0.53	V				
TJ	Range	- 40 to 175	C°				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-10WQ045FNHM3	UNITS			
Maximum DC reverse voltage	V _R	45	V			
Maximum working peak reverse voltage	V _{RWM}	40	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 157 °C, rectangular waveform		10	А		
Maximum peak one cycle non-repetitive surge current	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	400	A		
See fig. 7		10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	75			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 4.4 mH		20	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3.0	А		



D-PAK (TO-252AA)



PRODUCT SUMMARY								
Package	D-PAK (TO-252AA)							
I _{F(AV)}	10 A							
V _R	45 V							
V _F at I _F	0.53 V							
I _{RM}	15 mA at 125 °C							
T _J max.	175 °C							
Diode variation	Single die							
E _{AS}	20 mJ							

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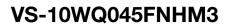
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COMPLIANT

HALOGEN

FREE





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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		10 A	T,I = 25 °C	0.63	V	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	1 j = 23 0	0.80		
See fig. 1	VFM \''	10 A	T _J = 125 °C	0.53		
		20 A		0.71		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C		1	mA	
See fig. 2		T _J = 125 °C	$V_R = Rated V_R$	15		
Threshold voltage	V _{F(TO)}	$-T_J = T_J$ maximum		0.255	V	
Forward slope resistance	r _t			22	mΩ	
Typical junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		760	pF	
Typical series inductance	LS	Measured lead to lead 5 mm from package body		5.0	nH	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

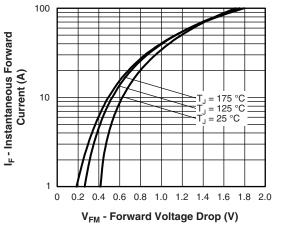
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 175	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	2.0	°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}		50	C/W		
Approximate weight			0.3	g		
Approximate weight			0.01	oz.		
Marking device		Case style D-PAK	10WQ0	45FNH		

Note

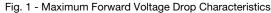
 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$

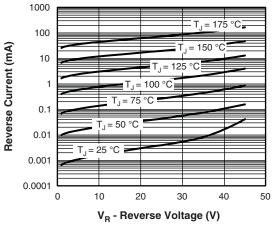
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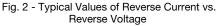
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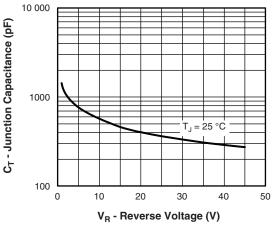


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

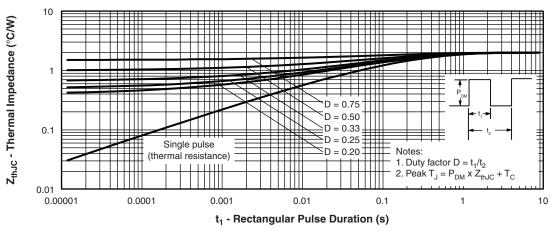


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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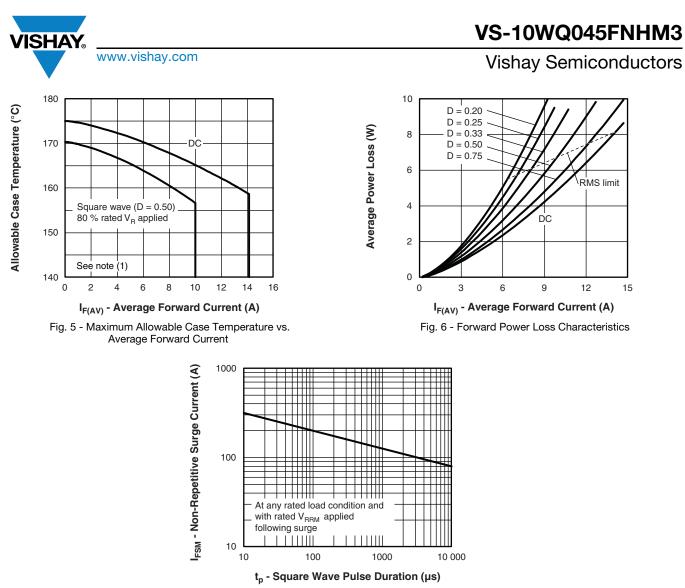


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \, x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$



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ISHA www.vishay.com

ORDERING INFORMATION TABLE

Device code	VS-	10	W	Q	045	FN	TRL	н	М3
	1	2	3	4	5	6	7	8	9
	1 .	· Visl	nay Sen	niconduo	ctors pro	oduct			
	2 -	- Cur	rent rati	ng (10 A	A)				
	3 -	- Pac	kage id	entifier:					
		VV =	D-PAK	ζ.					
	4 -	- Sch	ottky "C)" series					
	5 -	Volt	age rati	ng (045	= 45 V)				
	6	- FN	= TO-2	52AA (D	-PAK)				
	7	• N	one = T	ube					
		• TI	R = Tap	e and re	el				
		• TF	RL = Ta	pe and r	eel (left	oriente	d)		
		• TF	RR = Ta	pe and	reel (rigl	nt orien	ted)		
	8	- H=	AEC-Q	101 qua	alified				
	9 -			ntal digit en-free,		complia	int, and	termina	tions le

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R		MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-10WQ045FNHM3	75	3000	Antistatic plastic tube				
VS-10WQ045FNTRHM3	2000	2000	13" diameter reel				
VS-10WQ045FNTRRHM3	3000	3000	13" diameter reel				
VS-10WQ045FNTRLHM3	3000	3000	13" diameter reel				

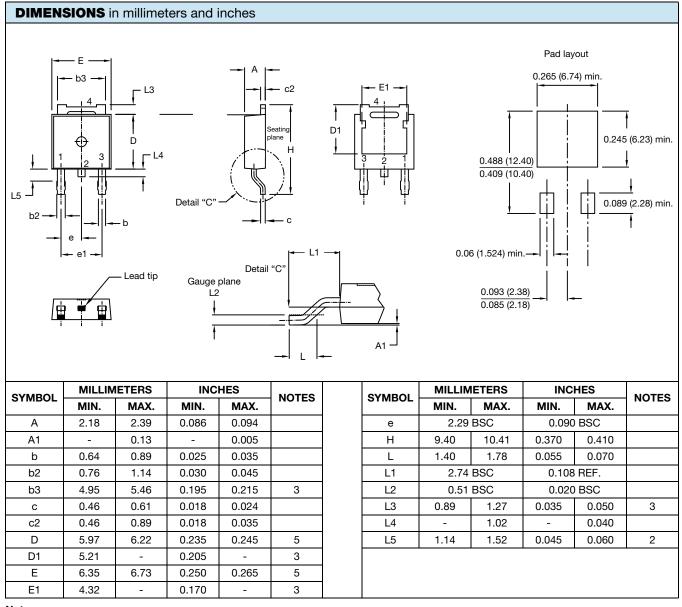
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95519				
Part marking information	www.vishay.com/doc?95518				
Packaging information	www.vishay.com/doc?95033				

Outline Dimensions



Vishay Semiconductors

DPAK (TO-252AA)



Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

⁽⁴⁾ Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Outline conforms to JEDEC[®] outline TO-252AA



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